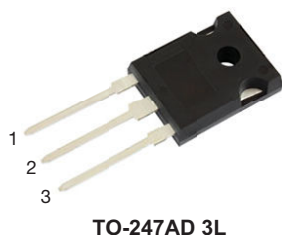
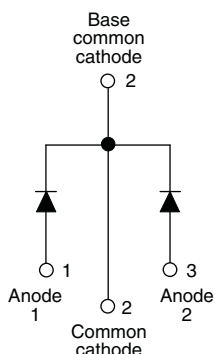


## Ultrafast Soft Recovery Diode, 2 x 30 A FRED Pt® Gen 4



TO-247AD 3L



### FEATURES

- Gen 4 FRED Pt® technology
- Low  $I_{RRM}$  and reverse recovery charge
- Very low forward voltage drop
- Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### PRIMARY CHARACTERISTICS

|                       |                    |
|-----------------------|--------------------|
| $I_{F(AV)}$           | 2 x 30 A           |
| $V_R$                 | 600 V              |
| $V_F$ at $I_F$        | 1.19 V             |
| $t_{rr}$ typ.         | See Recovery table |
| $T_J$ max.            | 175 °C             |
| Package               | TO-247AD 3L        |
| Circuit configuration | Common cathode     |

### DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow  $V_F$ , soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

### ABSOLUTE MAXIMUM RATINGS

| PARAMETER                                  | SYMBOL            | TEST CONDITIONS                                               | MAX.        | UNITS |
|--------------------------------------------|-------------------|---------------------------------------------------------------|-------------|-------|
| Peak repetitive reverse voltage            | $V_{RRM}$         |                                                               | 600         | V     |
| Average rectified forward current          | $I_{F(AV)}$       | $T_C = 131\text{ °C}$                                         | 30          | A     |
| Non-repetitive peak surge current, per leg | $I_{FSM}$         | $T_C = 25\text{ °C}$ , $t_p = 8.3\text{ ms}$ , half sine wave | 240         |       |
| Operating junction and storage temperature | $T_J$ , $T_{Stg}$ |                                                               | -55 to +175 | °C    |

### ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)

| PARAMETER                           | SYMBOL           | TEST CONDITIONS                             | MIN. | TYP. | MAX. | UNITS         |
|-------------------------------------|------------------|---------------------------------------------|------|------|------|---------------|
| Breakdown voltage, blocking voltage | $V_{BR}$ , $V_R$ | $I_R = 100\text{ }\mu\text{A}$              | 600  | -    | -    | V             |
| Forward voltage                     | $V_F$            | $I_F = 30\text{ A}$                         | -    | 1.36 | 1.6  |               |
|                                     |                  | $I_F = 60\text{ A}$                         | -    | 1.6  | -    |               |
|                                     |                  | $I_F = 30\text{ A}$ , $T_J = 125\text{ °C}$ | -    | 1.23 | -    |               |
|                                     |                  | $I_F = 60\text{ A}$ , $T_J = 125\text{ °C}$ | -    | 1.5  | -    |               |
|                                     |                  | $I_F = 30\text{ A}$ , $T_J = 150\text{ °C}$ | -    | 1.19 | 1.35 |               |
|                                     |                  | $I_F = 60\text{ A}$ , $T_J = 150\text{ °C}$ | -    | 1.48 | -    |               |
| Reverse leakage current             | $I_R$            | $V_R = V_R$ rated                           | -    | -    | 50   | $\mu\text{A}$ |
|                                     |                  | $T_J = 125\text{ °C}$ , $V_R = V_R$ rated   | -    | -    | 500  |               |
| Junction capacitance                | $C_T$            | $V_R = 600\text{ V}$                        | -    | 18.3 | -    | pF            |



| DYNAMIC RECOVERY CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise specified) |                  |                         |                                                                                    |      |      |      |       |
|--------------------------------------------------------------------------------------|------------------|-------------------------|------------------------------------------------------------------------------------|------|------|------|-------|
| PARAMETER                                                                            | SYMBOL           | TEST CONDITIONS         |                                                                                    | MIN. | TYP. | MAX. | UNITS |
| Reverse recovery time                                                                | t <sub>rr</sub>  | T <sub>J</sub> = 25 °C  | I <sub>F</sub> = 30 A<br>di <sub>F</sub> /dt = 1000 A/μs<br>V <sub>R</sub> = 400 V | -    | 65   | -    | ns    |
|                                                                                      |                  | T <sub>J</sub> = 125 °C |                                                                                    | -    | 90   | -    |       |
| Peak recovery current                                                                | I <sub>RRM</sub> | T <sub>J</sub> = 25 °C  |                                                                                    | -    | 18   | -    | A     |
|                                                                                      |                  | T <sub>J</sub> = 125 °C |                                                                                    | -    | 32   | -    |       |
| Reverse recovery charge                                                              | Q <sub>rr</sub>  | T <sub>J</sub> = 25 °C  |                                                                                    | -    | 850  | -    | nC    |
|                                                                                      |                  | T <sub>J</sub> = 125 °C |                                                                                    | -    | 1850 | -    |       |

| THERMAL - MECHANICAL SPECIFICATIONS   |                   |                        |            |      |            |                        |
|---------------------------------------|-------------------|------------------------|------------|------|------------|------------------------|
| PARAMETER                             | SYMBOL            | TEST CONDITIONS        | MIN.       | TYP. | MAX.       | UNITS                  |
| Thermal resistance, junction to case  | R <sub>thJC</sub> |                        | -          | -    | 1          | °C/W                   |
| Thermal resistance, case to heat sink | R <sub>thCS</sub> |                        | -          | 0.4  | -          |                        |
| Weight                                |                   |                        | -          | 6.0  | -          | g                      |
|                                       |                   |                        | -          | 0.21 | -          | oz.                    |
| Mounting torque                       |                   |                        | 6.0<br>(5) | -    | 12<br>(10) | kgf · cm<br>(lbf · in) |
| Marking device                        |                   | Case style TO-247AD 3L | C4PU3006LH |      |            |                        |

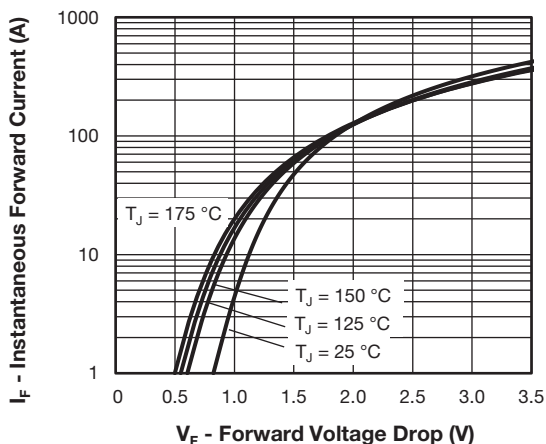


Fig. 1 - Typical Forward Voltage Drop Characteristics

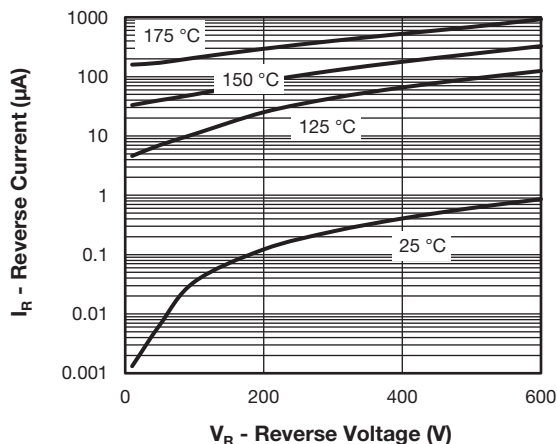


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

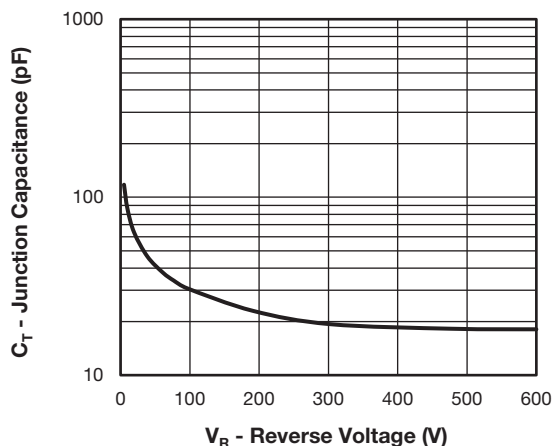


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

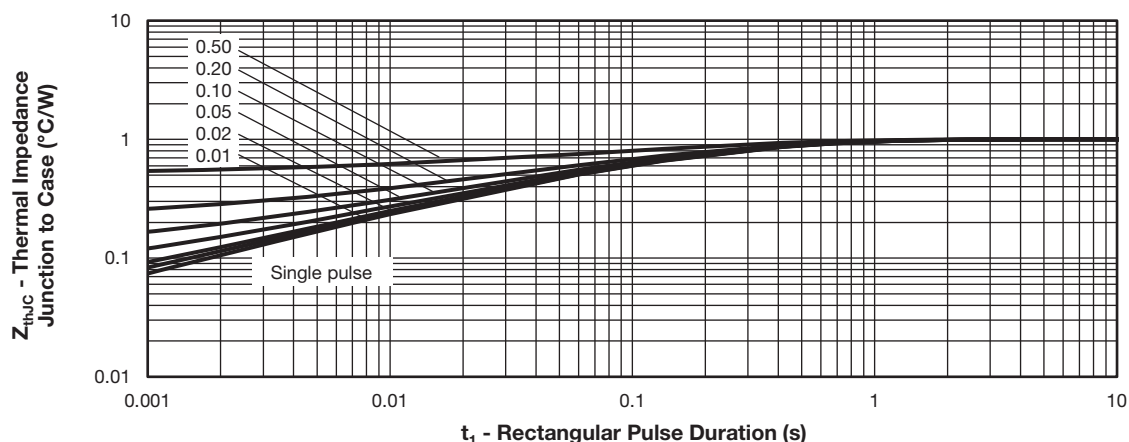
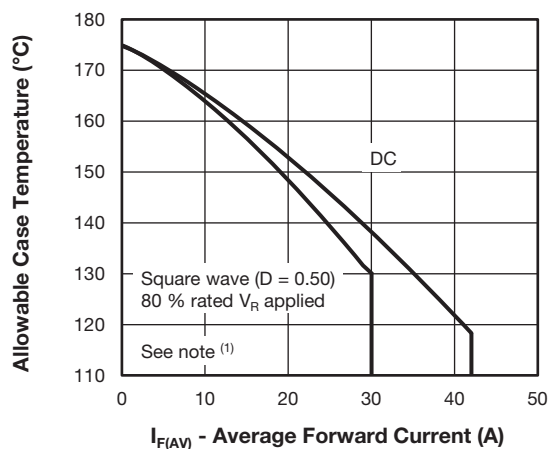

Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

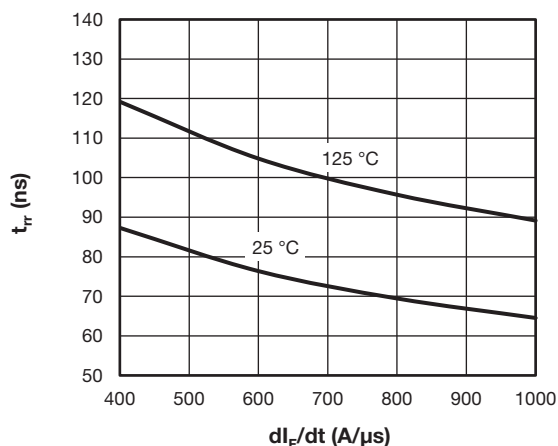
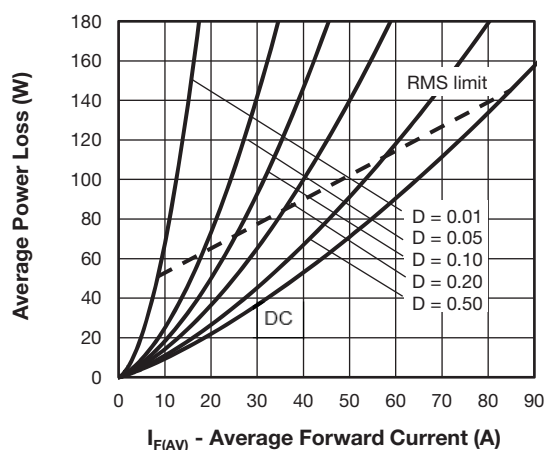
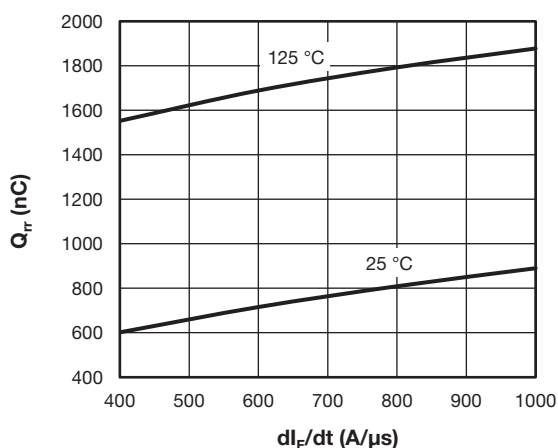

Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 


Fig. 6 - Forward Power Loss Characteristics


Fig. 8 - Typical Stored Charge vs.  $dI_F/dt$ 

#### Note

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see Fig.5)  
 $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_R$  = rated  $V_R$

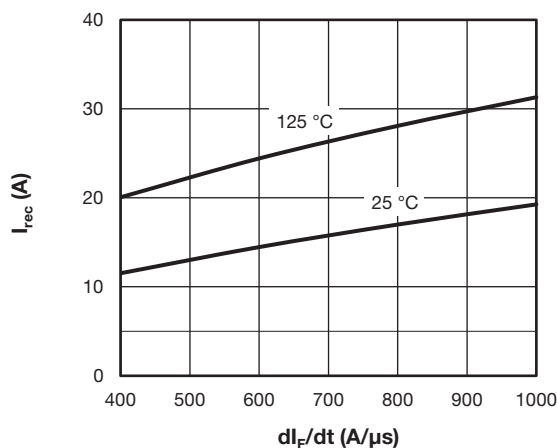


Fig. 9 - Typical Reverse Current vs.  $dl_F/dt$

## ORDERING INFORMATION TABLE

|             |     |   |   |   |   |    |    |   |   |    |
|-------------|-----|---|---|---|---|----|----|---|---|----|
| Device code | VS- | C | 4 | P | U | 60 | 06 | L | H | N3 |
|             | 1   | 2 | 3 | 4 | 5 | 6  | 7  | 8 | 9 | 10 |

- 1 - Vishay Semiconductors product
- 2 - Circuit configuration:  
C = common diode
- 3 - FRED Pt Gen 4
- 4 - P = TO-247 package
- 5 - Process type:  
U = ultrafast recovery
- 6 - Current rating (60 =  $2 \times 30$  A)
- 7 - Voltage rating (06 = 600 V)
- 8 - Package: L = long lead
- 9 - H = AEC-Q101 qualified
- 10 - Environmental digit:  
N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

| ORDERING INFORMATION (Example) |                   |                        |                         |
|--------------------------------|-------------------|------------------------|-------------------------|
| PREFERRED P/N                  | QUANTITY PER TUBE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION   |
| VS-C4PU6006LHN3                | 25                | 500                    | Antistatic plastic tube |

| LINKS TO RELATED DOCUMENTS |             |                                                                        |
|----------------------------|-------------|------------------------------------------------------------------------|
| Dimensions                 | TO-247AD 3L | <a href="http://www.vishay.com/doc?95626">www.vishay.com/doc?95626</a> |
| Part marking information   | TO-247AD 3L | <a href="http://www.vishay.com/doc?95007">www.vishay.com/doc?95007</a> |



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